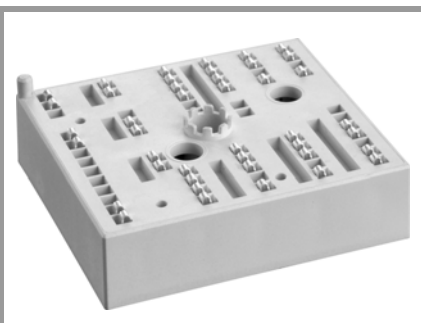


SKiiP 24ACC12T7V1



MiniSKiiP® 2

Twelvepack

SKiiP 24ACC12T7V1

Features*

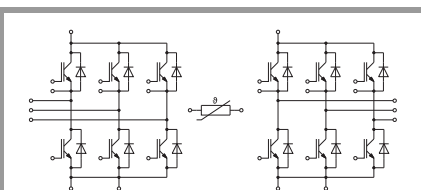
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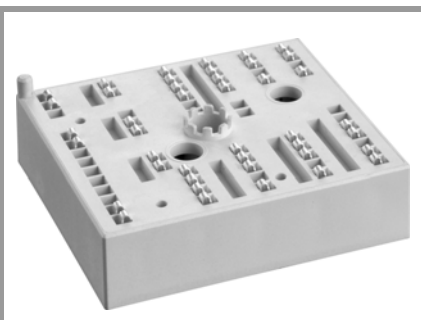
Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
Inverter - IGBT				
V_{CES}	$T_j = 25\text{ °C}$		1200	V
I_C	$\lambda_{paste}=0.8\text{ W/(mK)}$	$T_s = 70\text{ °C}$	42	A
		$T_j = 175\text{ °C}$	34	A
I_C	$\lambda_{paste}=2.5\text{ W/(mK)}$	$T_s = 70\text{ °C}$	47	A
		$T_j = 175\text{ °C}$	38	A
I_{Chom}			35	A
I_{CRM}			70	A
V_{GES}			-20 ... 20	V
t_{psc}	$V_{CC} = 800\text{ V}$	$T_j = 175\text{ °C}$	7	μs
	$V_{GE} \leq 15\text{ V}$			
	$V_{CES} \leq 1200\text{ V}$			
T_j			-40 ... 175	$^{\circ}\text{C}$
Inverse - Diode				
I_F	$\lambda_{paste}=0.8\text{ W/(mK)}$	$T_s = 70\text{ °C}$	33	A
		$T_j = 175\text{ °C}$	27	A
I_F	$\lambda_{paste}=2.5\text{ W/(mK)}$	$T_s = 70\text{ °C}$	37	A
		$T_j = 175\text{ °C}$	30	A
I_{FRM}			70	A
I_{FSM}	$t_p = 10\text{ ms, sin } 180^{\circ}, T_j = 150\text{ °C}$		170	A
T_j			-40 ... 175	$^{\circ}\text{C}$
Module				
$I_{t(RMS)}$	$T_{terminal} = 80\text{ °C}, 20\text{ A per spring}$		40	A
T_{stg}	module without TIM		-40 ... 125	$^{\circ}\text{C}$
V_{isol}	AC sinus 50 Hz, $t = 1\text{ min}$		2500	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverter - IGBT						
$V_{CE(sat)}$	$I_C = 35\text{ A}$	$T_j = 25\text{ °C}$	1.60	1.75		V
		$T_j = 150\text{ °C}$	1.82	1.96		V
		chiplevel	1.86	2.00		V
V_{CE0}	chiplevel	$T_j = 25\text{ °C}$	0.90	1.00		V
		$T_j = 150\text{ °C}$	0.75	0.83		V
		$T_j = 175\text{ °C}$	0.72	0.80		V
r_{CE}	$V_{GE} = 15\text{ V}$ chiplevel	$T_j = 25\text{ °C}$	20	21		$\text{m}\Omega$
		$T_j = 150\text{ °C}$	31	32		$\text{m}\Omega$
		$T_j = 175\text{ °C}$	33	34		$\text{m}\Omega$
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0.75\text{ mA}$		5.15	5.8	6.45	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = 1200\text{ V}, T_j = 25\text{ °C}$				1	mA
C_{ies}	$V_{CE} = 25\text{ V}$ $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	6.60			nF
C_{oes}		$f = 1\text{ MHz}$	0.09			nF
C_{res}		$f = 1\text{ MHz}$	0.02			nF
Q_G	$V_{GE} = -8\text{ V} \dots +15\text{ V}$		490			nC
R_{Gint}	$T_j = 25\text{ °C}$		0			Ω



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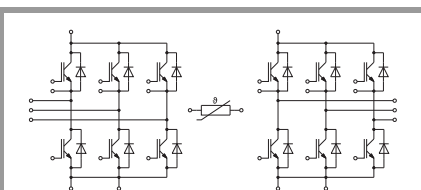
SKiiP 24ACC12T7V1

Features*

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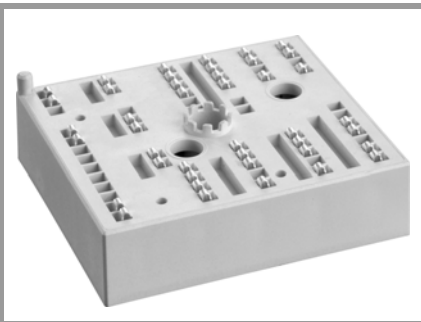


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Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
Inverter - IGBT					
$t_{d(on)}$		$T_j = 25\text{ °C}$	37		ns
		$T_j = 150\text{ °C}$	39		ns
		$T_j = 175\text{ °C}$	40		ns
t_r		$T_j = 25\text{ °C}$	37		ns
		$T_j = 150\text{ °C}$	43		ns
		$T_j = 175\text{ °C}$	46		ns
E_{on}	$V_{CC} = 600\text{ V}$ $I_C = 35\text{ A}$ $R_{G, on} = 9.1\ \Omega$ $R_{G, off} = 9.1\ \Omega$ $V_{GE} = +15/-15\text{ V}$	$T_j = 25\text{ °C}$	2.8		mJ
		$T_j = 150\text{ °C}$	4		mJ
		$T_j = 175\text{ °C}$	4.2		mJ
$t_{d(off)}$		$T_j = 25\text{ °C}$	231		ns
		$T_j = 150\text{ °C}$	321		ns
		$T_j = 175\text{ °C}$	346		ns
t_f	@ $T_j = 150\text{ °C}$: $di/dt_{on} = 860\text{ A}/\mu\text{s}$ $di/dt_{off} = 380\text{ A}/\mu\text{s}$ $dv/dt = 3610\text{ V}/\mu\text{s}$	$T_j = 25\text{ °C}$	48		ns
		$T_j = 150\text{ °C}$	74		ns
		$T_j = 175\text{ °C}$	90		ns
E_{off}		$T_j = 25\text{ °C}$	2.3		mJ
		$T_j = 150\text{ °C}$	3.9		mJ
		$T_j = 175\text{ °C}$	4.2		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$		1.12		K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$		0.93		K/W

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
Inverse - Diode					
$V_F = V_{EC}$	$I_F = 35\text{ A}$ $V_{GE} = 0\text{ V}$ chiplevel	$T_j = 25\text{ °C}$	2.30	2.62	V
		$T_j = 150\text{ °C}$	2.29	2.62	V
		$T_j = 175\text{ °C}$	2.14	2.46	V
V_{F0}	chiplevel	$T_j = 25\text{ °C}$	1.30	1.50	V
		$T_j = 150\text{ °C}$	0.90	1.10	V
		$T_j = 175\text{ °C}$	0.82	0.98	V
r_F	chiplevel	$T_j = 25\text{ °C}$	29	32	m Ω
		$T_j = 150\text{ °C}$	40	43	m Ω
		$T_j = 175\text{ °C}$	38	42	m Ω
I_{RRM}		$T_j = 25\text{ °C}$	22		A
		$T_j = 150\text{ °C}$	28		A
		$T_j = 175\text{ °C}$	33		A
Q_{rr}	$I_F = 35\text{ A}$ $V_{GE} = +15/-15\text{ V}$ $V_{CC} = 600\text{ V}$	$T_j = 25\text{ °C}$	2		μC
		$T_j = 150\text{ °C}$	5.2		μC
		$T_j = 175\text{ °C}$	5.7		μC
E_{rr}	@ $T_j = 150\text{ °C}$: $di/dt_{off} = 870\text{ A}/\mu\text{s}$	$T_j = 25\text{ °C}$	0.65		mJ
		$T_j = 150\text{ °C}$	2.1		mJ
		$T_j = 175\text{ °C}$	2.7		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$		1.34		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$		1.13		K/W
Module					
L_{CE}			-		nH
M_s	to heat sink	2		2.5	Nm
w			55		g

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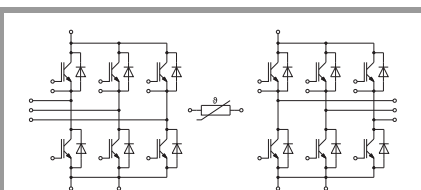
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Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
Temperature Sensor					
R_{100}	$T_r=100\text{ °C}$ ($R_{25}=1000\Omega$)		$1670 \pm 3\%$		Ω
$R_{(T)}$	$R_{(T)}=1000\Omega[1+A(T-25\text{ °C})+B(T-25\text{ °C})^2]$ $A = 7.635 \cdot 10^{-3}\text{ °C}^{-1}$, $B = 1.731 \cdot 10^{-5}\text{ °C}^{-2}$				



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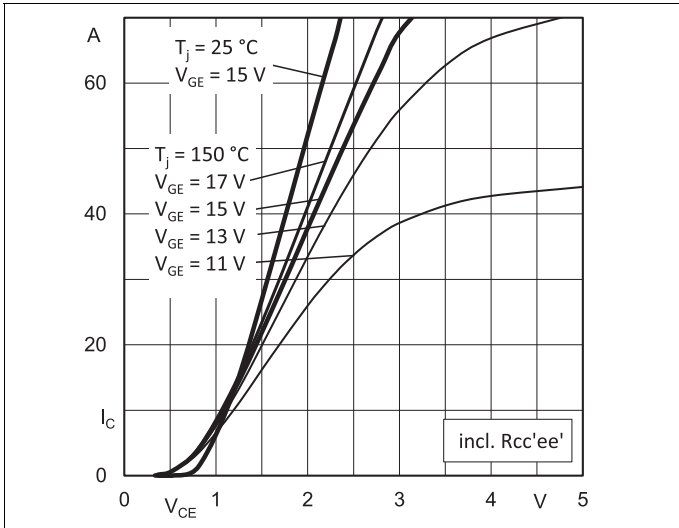


Fig. 1: Typ. output characteristic

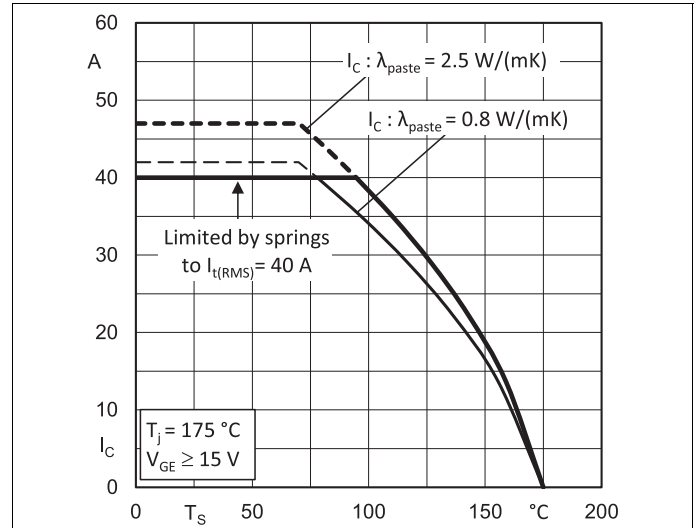


Fig. 2: Rated current vs. temperature $I_C = f(T_S)$

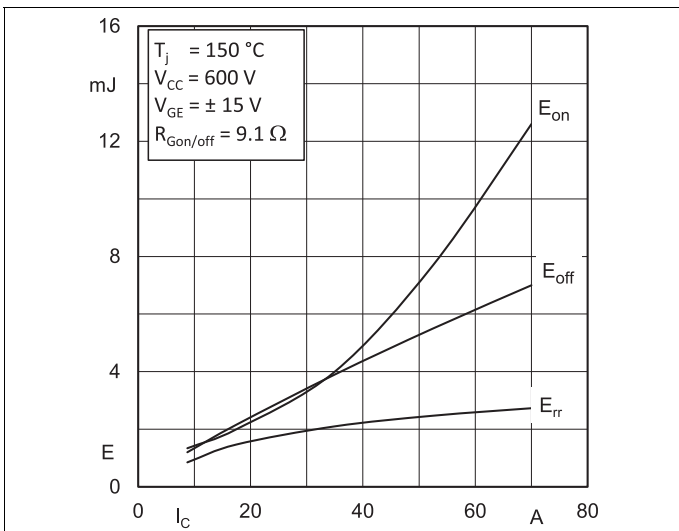


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

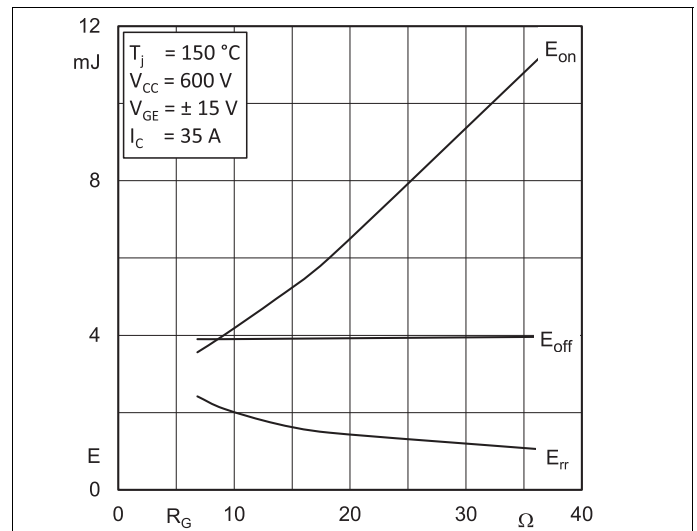


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

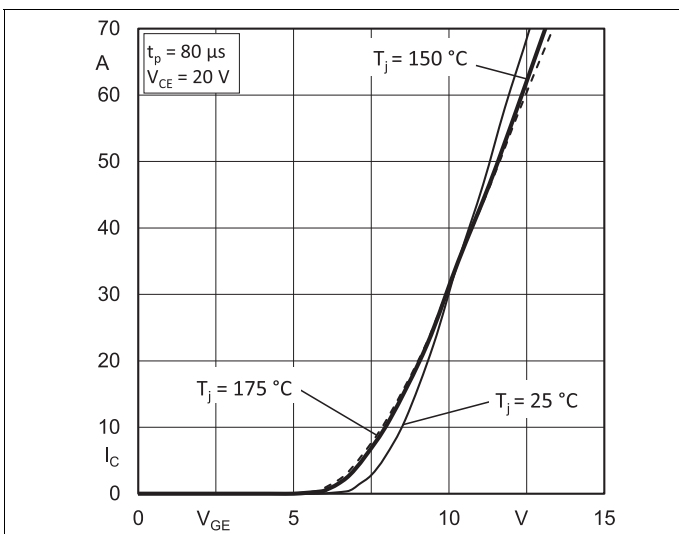


Fig. 5: Typ. transfer characteristic

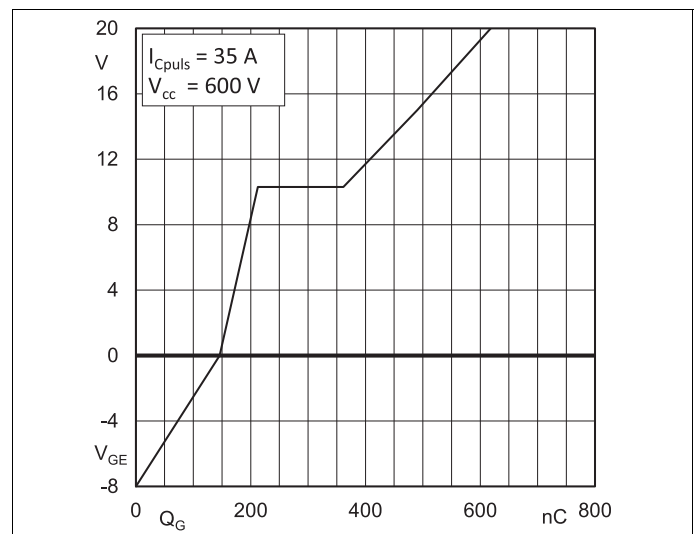


Fig. 6: Typ. gate charge characteristic

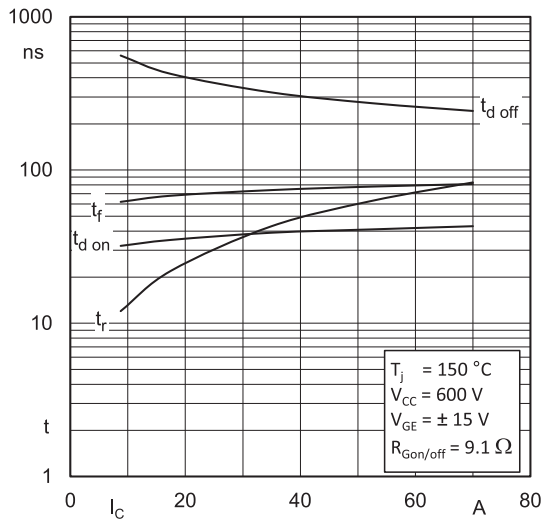


Fig. 7: Typ. switching times vs. I_C

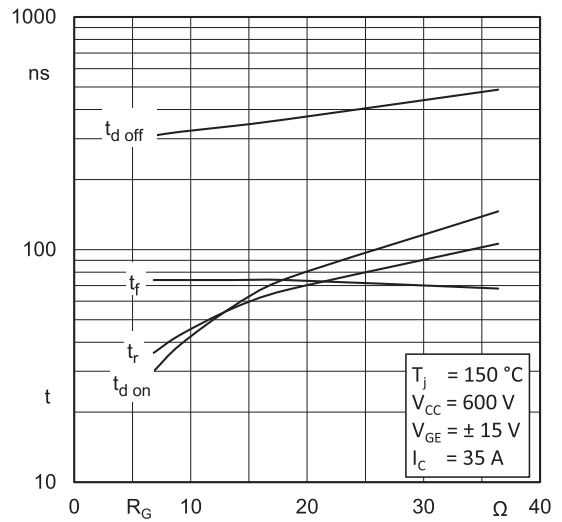


Fig. 8: Typ. switching times vs. gate resistor R_G

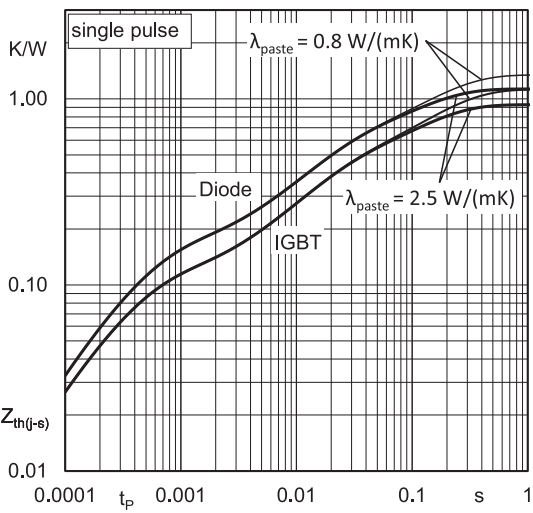


Fig. 9: Transient thermal impedance

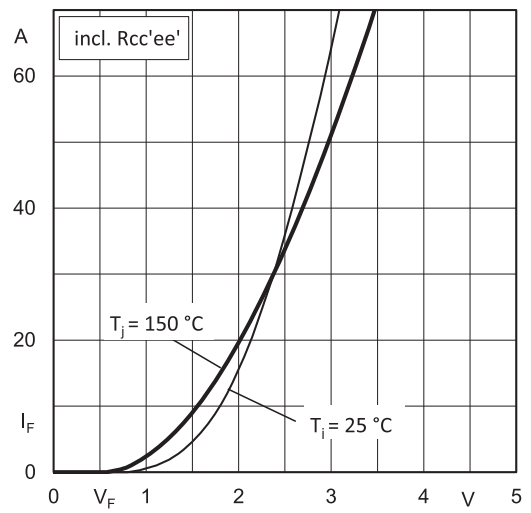


Fig. 10: Typ. CAL diode forward characteristic

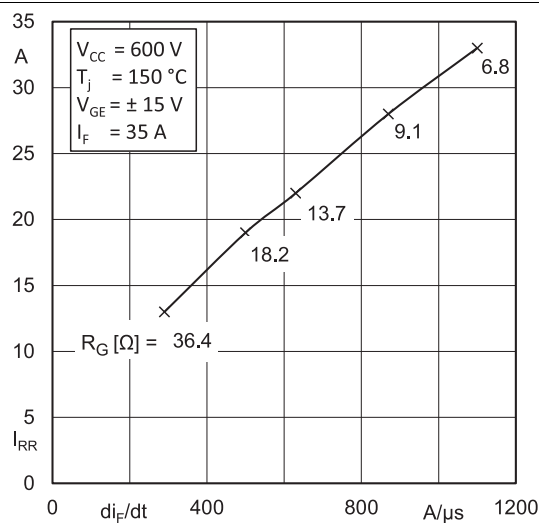


Fig. 11: Typ. CAL diode peak reverse recovery current

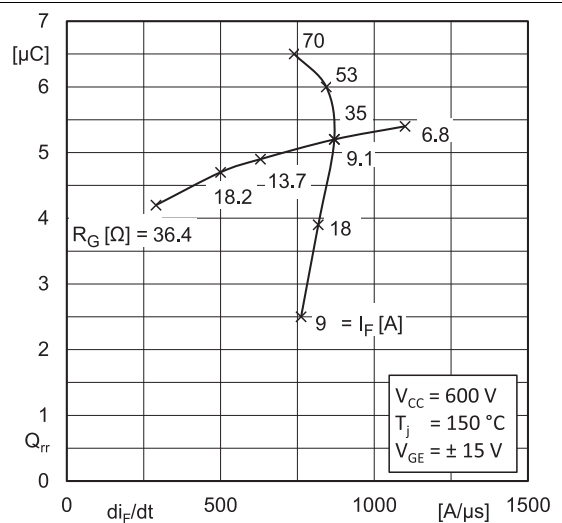
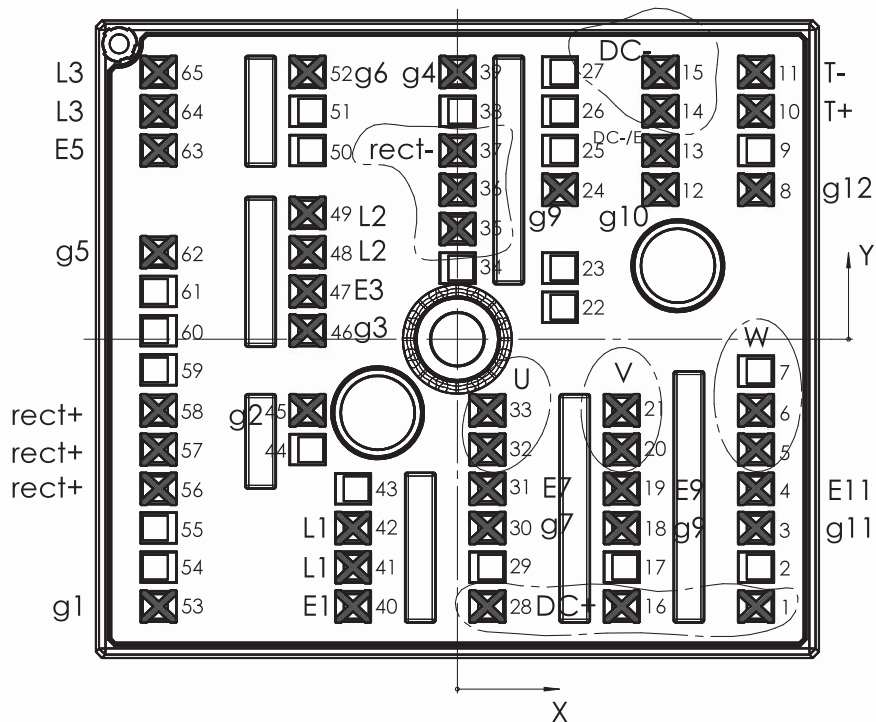
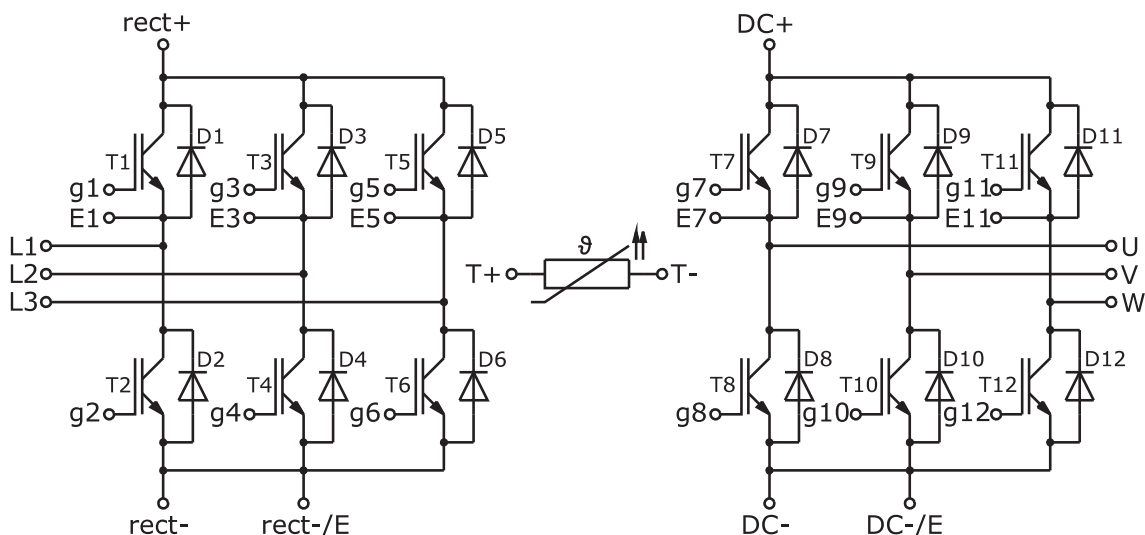


Fig. 12: Typ. CAL diode recovery charge

Pin out											
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	24,38	-21,8	DC+	23				45	-12,23	-5,8	g2
2				24	8,38	12,2	g9	46	-12,23	0,7	g3
3	24,38	-15,4	g11	25				47	-12,23	3,9	E3
4	24,38	-12,2	E11	26				48	-12,23	7,1	L2
5	24,38	-9	W	27				49	-12,23	10,3	L2
6	24,38	-5,8	W	28	2,46	-21,8	DC+	50			
7				29				51			
8	24,38	12,2	g12	30	2,46	-15,4	g7	52	-12,23	21,8	g6
9				31	2,46	-12,2	E7	53	-24,38	-21,8	g1
10	24,38	18,6	T+	32	2,46	-9	U	54			
11	24,38	21,8	T-	33	2,46	-5,8	U	55			
12	16,58	12,2	g10	34				56	-24,38	-12,2	rect+
13	16,58	15,4	DC-/E	35	0,03	9	rect-	57	-24,38	-9	rect+
14	16,58	18,6	DC-	36	0,03	12,2	rect-	58	-24,38	-5,8	rect+
15	16,58	21,8	DC-	37	0,03	15,4	rect-	59			
16	13,42	-21,8	DC+	38				60			
17				39	0,03	21,8	g4	61			
18	13,42	-15,4	g9	40	-8,51	-21,8	E1	62	-24,38	7,1	g5
19	13,42	-12,2	E9	41	-8,51	-18,6	L1	63	-24,38	15,4	E5
20	13,42	-9	U	42	-8,51	-15,4	L1	64	-24,38	18,6	L3
21	13,42	-5,8	U	43				65	-24,38	21,8	L3
22				44							

all values in mm





Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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